

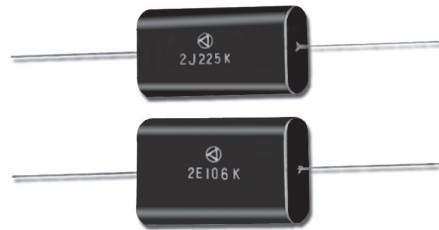


特性

- 高频、高电流耐量
- 横卧式大容量系列

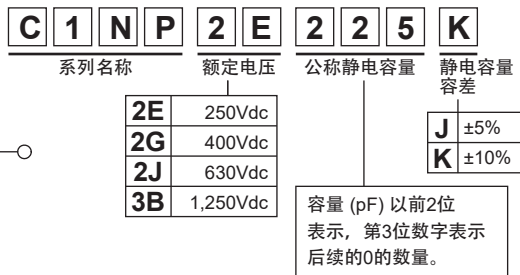
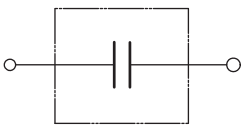
用途

- IGBT、IPM等半导体设备的保护（缓冲电路）
- 开关电源、变频器/伺服设备等

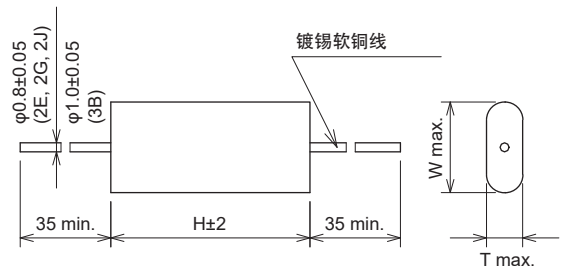


型号配置

● 电路图



● 外形尺寸



※容许电流特性请咨询当地销售办事处。

单位: mm

额定电压	型号	静电容量 μF	外形尺寸 (mm)				介电损耗 角正切	测试电压 (线对线)	绝缘电阻 (线对线)
			W	H	T	φd			
2E (250Vdc)	C1NP2E225□	2.2	20.0	44.0	8.0	0.001max. (at 1kHz)	额定电压×1.75Vdc (2~5sec)	20000Ω·Fmin. (at 20°C, 100Vdc)	
	C1NP2E275□	2.7	21.5	44.0	9.0				
	C1NP2E335□	3.3	22.0	44.0	10.5				
	C1NP2E395□	3.9	23.5	44.0	11.5				
	C1NP2E475□	4.7	25.0	44.0	13.0				
	C1NP2E565□	5.6	27.0	44.0	14.5				
	C1NP2E685□	6.8	28.5	44.0	16.5				
	C1NP2E825□	8.2	33.5	44.0	17.5				
	C1NP2E106□	10	34.5	44.0	19.5				
2G (400Vdc)	C1NP2G125□	1.2	20.5	44.0	9.0	0.001max. (at 1kHz)	额定电压×1.75Vdc (2~5sec)	20000Ω·Fmin. (at 20°C, 100Vdc)	
	C1NP2G155□	1.5	22.0	44.0	10.5				
	C1NP2G185□	1.8	23.5	44.0	11.5				
	C1NP2G225□	2.2	25.0	44.0	13.0				
	C1NP2G275□	2.7	26.5	44.0	14.5				
	C1NP2G335□	3.3	28.5	44.0	16.5				
	C1NP2G395□	3.9	32.0	44.0	17.5				
2J (630Vdc)	C1NP2J824□	0.82	20.5	44.0	9.5	0.001max. (at 1kHz)	额定电压×1.75Vdc (2~5sec)	20000Ω·Fmin. (at 20°C, 100Vdc)	
	C1NP2J105□	1.0	21.5	44.0	10.0				
	C1NP2J125□	1.2	23.0	44.0	11.5				
	C1NP2J155□	1.5	24.5	44.0	13.0				
	C1NP2J185□	1.8	26.5	44.0	14.5				
	C1NP2J225□	2.2	28.0	44.0	16.0				
	C1NP2J275□	2.7	30.5	44.0	17.5				
3B (1250Vdc)	C1NP3B105□	1.0	30.0	60.0	20.5	0.001max. (at 1kHz)	额定电压×1.75Vdc (2~5sec)	20000Ω·Fmin. (at 20°C, 100Vdc)	
	C1NP3B125□	1.2	32.5	60.0	23.0				
	C1NP3B155□	1.5	35.5	60.0	26.0				
	C1NP3B185□	1.8	38.5	60.0	29.0				
	C1NP3B225□	2.2	38.0	70.0	28.5				
	C1NP3B275□	2.7	41.5	70.0	32.0				
	C1NP3B335□	3.3	45.5	70.0	36.0				
C1NP3B395□	3.9	49.0	70.0	39.5					
C1NP3B475□	4.7	53.0	70.0	44.0					

□: 静电容量容差 J(±5%)、K(±10%)

使用温度范围: -40~+85°C